

## **KSC2330A**

### **Color TV Chroma Output**

- Collector-Base Voltage: V<sub>CBO</sub>=400V
  Current Gain Bandwidth Product: f<sub>T</sub>=50MHz (TYP.)



### 1. Emitter 2. Collector 3. Base

## **NPN Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

| Symbol           | Parameter                   | Ratings    | Units |
|------------------|-----------------------------|------------|-------|
| $V_{CBO}$        | Collector-Base Voltage      | 400        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage   | 400        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage        | 7          | V     |
| I <sub>C</sub>   | Collector Current           | 100        | mA    |
| P <sub>C</sub>   | Collector Power Dissipation | 1          | W     |
| TJ               | Junction Temperature        | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature         | -55 ~ +150 | °C    |

## **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

| Symbol                | Parameter                            | Test Condition                                  | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|---|------|------|------|-------|
| BV <sub>CBO</sub>     | Collector-Base Breakdown Voltage     | $I_C=100\mu A, I_E=0$                           | 400  |      |      | V     |
| BV <sub>CEO</sub>     | Collector-Emitter Breakdown Voltage  | $I_C=5mA$ , $I_B=0$                             | 400  |      |      | V     |
| BV <sub>EBO</sub>     | Emitter-Base Breakdown Voltage       | $I_E=100\mu A, I_C=0$                           | 7    |      |      | V     |
| I <sub>CBO</sub>      | Collector Cut-off Current            | V <sub>CB</sub> =200V, I <sub>E</sub> =0        |      |      | 0.1  | μΑ    |
| h <sub>FE</sub>       | DC Current Gain                      | V <sub>CE</sub> =10V, I <sub>C</sub> =20mA      | 40   |      | 80   |       |
| V <sub>CE</sub> (sat) | Collector-Emitter Saturation Voltage | I <sub>C</sub> =10mA, I <sub>B</sub> =1mA       |      |      | 0.5  | V     |
| f <sub>T</sub>        | Current Gain Bandwidth Product       | V <sub>CE</sub> =30V, I <sub>C</sub> =10mA      |      | 50   |      | MHz   |
| C <sub>ob</sub>       | Output Capacitance                   | V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz |      | 4    |      | pF    |

## **h**<sub>FE</sub> Classification

| Classification  | R       | 0       |  |
|-----------------|---------|---------|--|
| h <sub>FE</sub> | 40 ~ 65 | 55 ~ 80 |  |

# **Typical Characteristics**

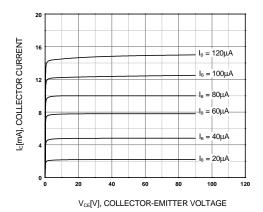


Figure 1. Static Characteristic

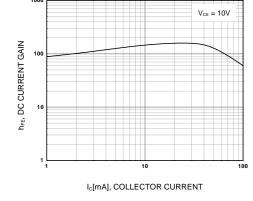


Figure 2. DC current Gain

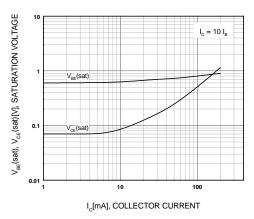


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

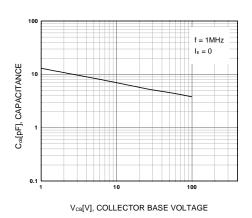


Figure 4. Collector Output Capacitance

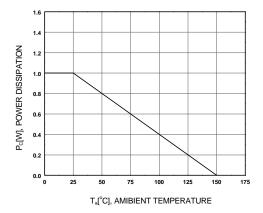
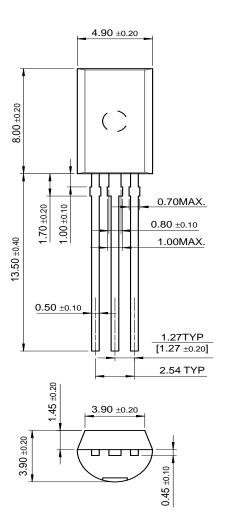


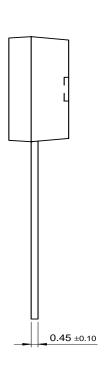
Figure 5. Power Derating



# **Package Dimensions**

TO-92L





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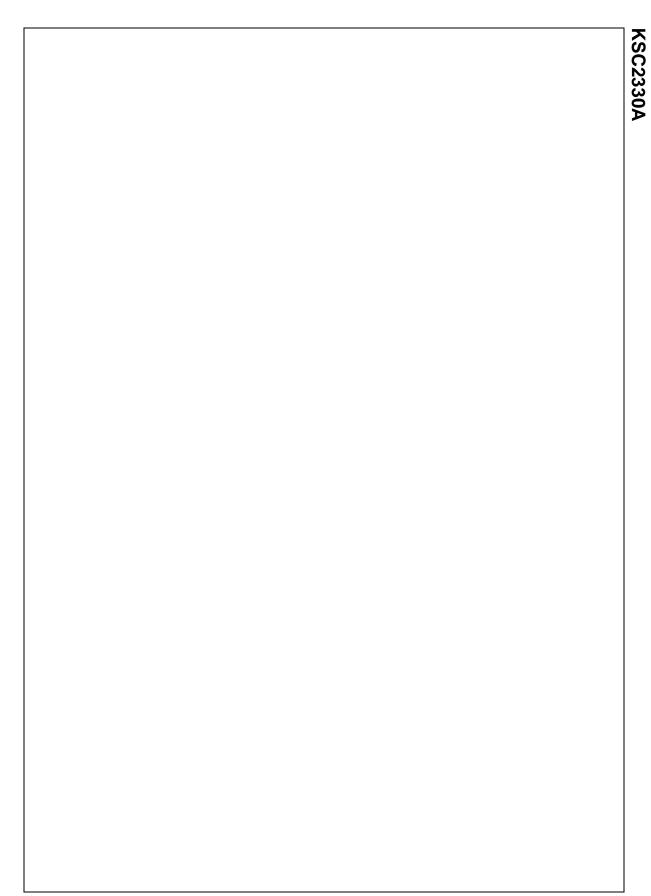
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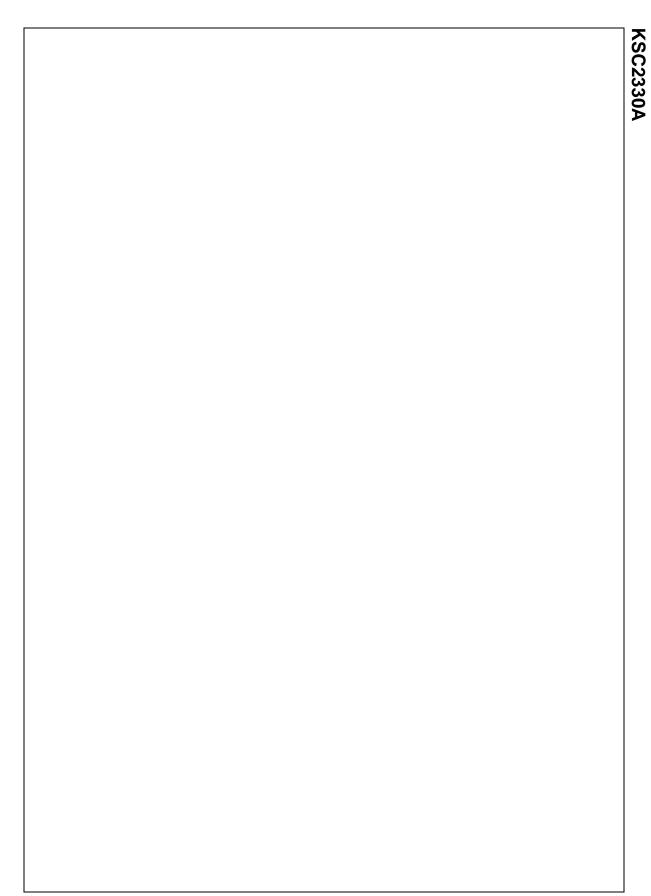
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